Silicon P Channel MOS FET High Speed Power Switching

# HITACHI

ADE-208-519 1st. Edition

#### Features

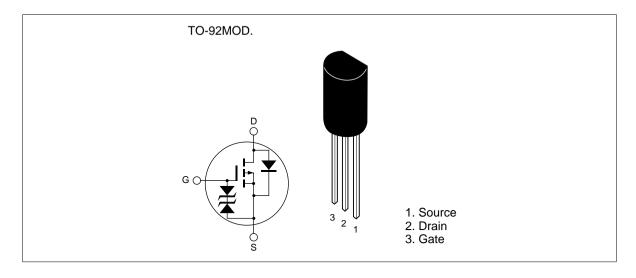
Low on-resistance

 $R_{DS(on)} = 0.08\Omega$  typ (at  $V_{GS} = -10$  V,  $I_D = -2.5$  A)

- 4V gate drive devices.
- Large current capacitance

$$I_D = -5 A$$

#### Outline





# **Absolute Maximum Ratings** (Ta = $25^{\circ}$ C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	-30	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	-5	А
Drain peak current	Note1 D(pulse)	-20	А
Body to drain diode reverse drain current	I <sub>DR</sub>	-5	А
Channel dissipation	Pch	0.9	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

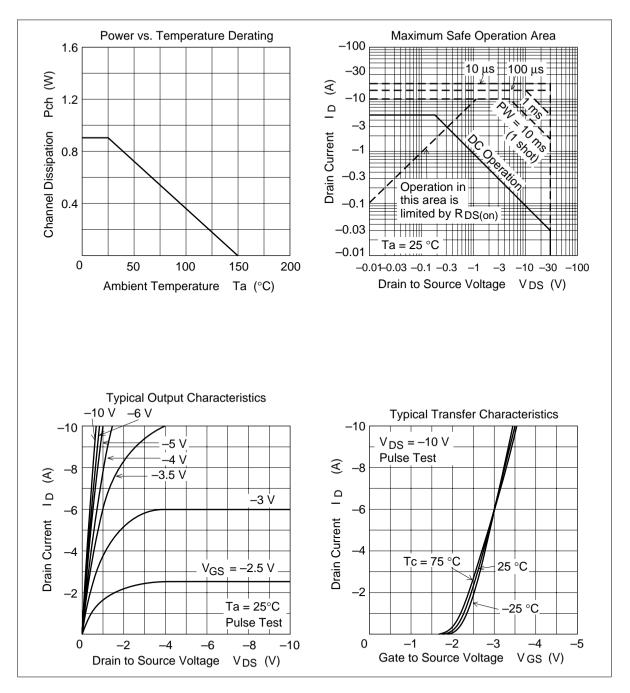
Note: 1. PW  $\leq$  10µs, duty cycle  $\leq$  1 %

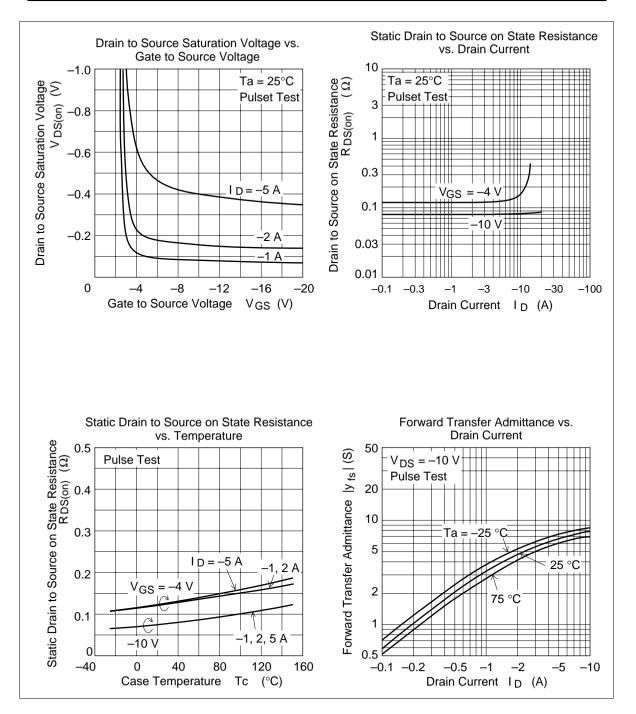
# **Electrical Characteristics** (Ta = 25°C)

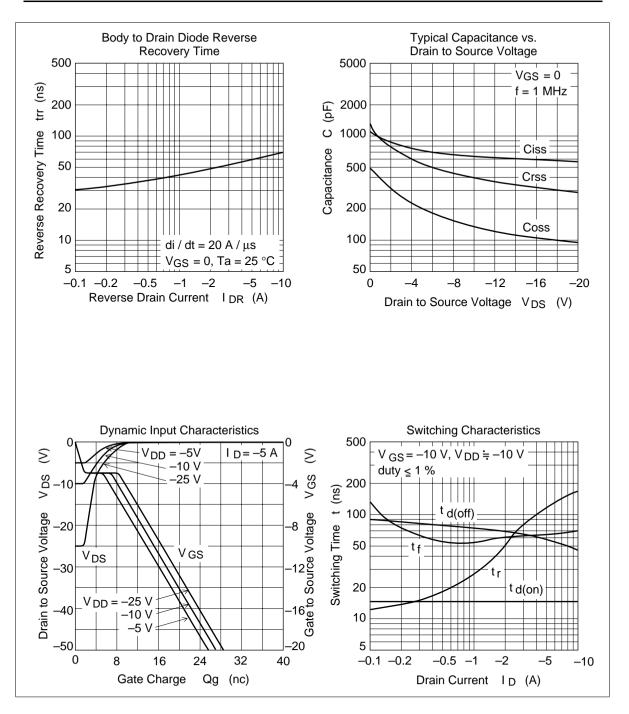
V <sub>(BR)DSS</sub> V <sub>(BR)GSS</sub> I <sub>DSS</sub> I <sub>GSS</sub> V <sub>GS(off)</sub> R <sub>DS(on)</sub>	-30 ±20  -1.0 			ν ν μΑ μΑ	$I_{D} = -10 \text{mA}, V_{GS} = 0$ $I_{G} = \pm 100 \mu \text{A}, V_{DS} = 0$ $V_{DS} = -30 \text{ V}, V_{GS} = 0$
I <sub>DSS</sub> I <sub>GSS</sub> V <sub>GS(off)</sub>			±10	μA	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0$
I <sub>GSS</sub> V <sub>GS(off)</sub>	— — —1.0		±10		
V <sub>GS(off)</sub>	— —1.0 —	_		μA	
_	-1.0 	—	0.0		$V_{GS} = \pm 16V, V_{DS} = 0$
$R_{DS(on)}$			-2.0	V	$I_{\rm D} = -1$ mA, $V_{\rm DS} = -10$ V
		0.08	0.11	Ω	$I_{\rm D} = -2.5 {\rm A}$ $V_{\rm GS} = -10 {\rm V}^{*1}$
$R_{\text{DS(on)}}$	—	0.12	0.17	Ω	$I_{\rm D} = -2.5 {\rm A}$ $V_{\rm GS} = -4 {\rm V}^{*1}$
y <sub>fs</sub>	3	5	_	S	$I_{\rm D} = -2.5 {\rm A},$ $V_{\rm DS} = -10 {\rm V}^{*1}$
Ciss	_	630	_	pF	$V_{DS} = -10V$
Coss	_	390	_	pF	$V_{GS} = 0$
Crss	_	135		pF	f = 1MHz
t <sub>d(on)</sub>	_	15	_	ns	$V_{GS} = -10V, I_{D} = -2.5A$
t,	_	70	_	ns	$R_{L} = 4\Omega$
t <sub>d(off)</sub>	_	65	—	ns	
t <sub>f</sub>	_	60	_	ns	
$V_{DF}$	_	-1.0	—	V	$I_{\rm D} = -5A, V_{\rm GS} = 0$
t <sub>rr</sub>	—	60	—	ns	$I_F = -5A$ , $V_{GS} = 0$ diF/ dt = 20A/µs
	y <sub>ts</sub>             Cisss           Coss           Crss           t <sub>d(off)</sub> t <sub>f</sub> V <sub>DF</sub>	$\begin{array}{   c    c   c   c   c   c   c   c   c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

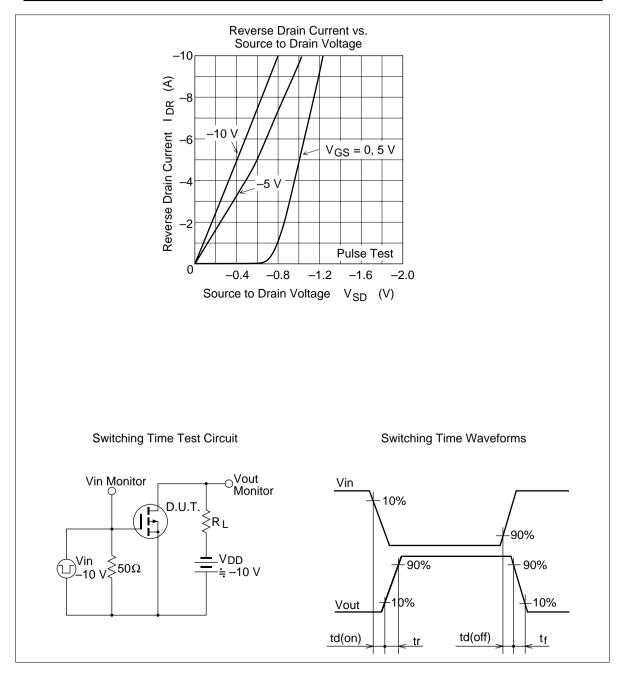
Note: 1. Pulse test

#### **Main Characteristics**



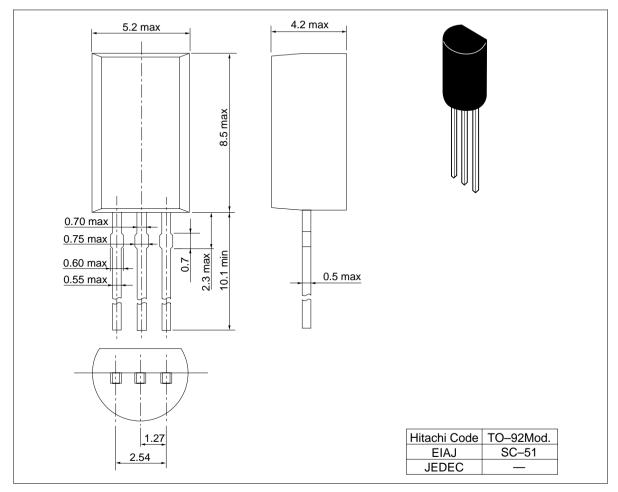






# **Package Dimensions**

Unit: mm



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